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Inclosure Material:	
Metal	
Overall Length:	
1.253 inches	
Function For Which	Designed:
Voltage regulator	
Mounting Facility Qu	antity:
1	
Joint Electronic Dev	ce Engineering Council/jedec/case Outline Designation:
Do-4	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed ca	ase and quality assurance level txv
Overall Width Acros	s Flats:
0.505 inches	
Thread Size:	
0.190 inches	
Semiconductor Mate	rial:
Silicon	
Voltage Rating In Vo	Its Per Characteristic:
30.0 regulator voltag	e
Current Rating Per C	haracteristic:
85.00 milliamperes so	urce cutoff current horsepower metric
Power Rating Per Ch	aracteristic:
10.0 watts small-signa	l input power, common-collector preset
Maximum Operating	Tempurature Per Measurement Point:
175.0 degrees celsius	junction
Test Data Document	
81349-mil-s-19500 sp	ecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes com	mercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and pe	formance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Desig	nator:
Unf	
Terminal Type And G	Quantity:
1 tab, solder lug and	1 threaded stud
Specification Data:	
81349-mil-s-19500/12	4 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	

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